COMPLIANT



Vishay Siliconix

# **Buffered H-Bridge Driver with Integrate MOSFET**

#### **DESCRIPTION**

The Si9986 is an integrated, buffered H-bridge with TTL compatible inputs and the capability of delivering a continuous 1 A at  $V_{DD}$  = 12 V (room temperature) at switching rates up to 200 kHz. Internal logic prevents the upper and lower outputs of either half-bridge from being turned on simultaneously. Unique input codes allow both outputs to be forced low (for braking) or forced to a high impedance level.

The Si9986 is available in both standard and lead (Pb)-free, 8-pin SOIC packages, specified to operate over a voltage range of 3.8 V to 13.2 V, and the commercial temperature range of 0 °C to 70 °C (C suffix) and the industrial temperature range of - 40 °C to 85 °C (D suffix).

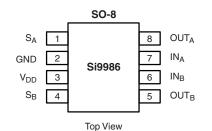
#### **FEATURES**

- 1 A H-bridge
- 200 kHz switching rate
- Shoot-through limited
- TTL compatible inputs
- 3.8 V to 13.2 V operating range
- Surface mount packaging

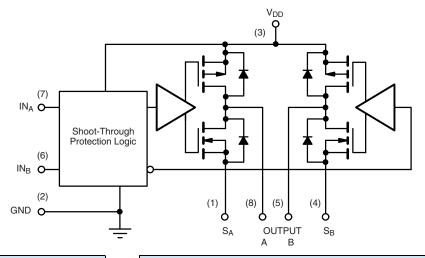
### **APPLICATIONS**

- VCM driver
- Brushed motor driver
- Stepper motor driver
- Power converter
- Optical disk drives
- Power supplies
- High performance servo

#### FUNCTIONAL BLOCK DIAGRAM, PIN CONFIGURATION AND TRUTH TABLE



TRUTH TABLE					
INA	IN <sub>B</sub>	OUTA	OUTB		
1	0	1	0		
0	1	0	1		
0	0	0	0		
1	1	HiZ	HiZ		



PIN DESCRIPTION				
Pin Number	Name	Function		
1	S <sub>A</sub>	Source of the low-side MOSFET on bridge arm A		
2	GND	Ground		
3	$V_{DD}$	IC power supply		
4	S <sub>B</sub>	Source of the low-side MOSFET on bridge arm B		
5	OUTB	Center tap of bridge arm B. Connects to one end of the load		
6	IN <sub>B</sub>	Input signal to control bridge arm B		
7	IN <sub>A</sub>	Input signal to control bridge arm A		
8	OUT <sub>A</sub>	Center tap of bridge arm A. Connects to the other end of the load		

ORDERING INFORMATION					
Part Number	Temperature Range	Package			
Si9986CY-T1	0 °C to 70 °C	Tape and reel			
Si9986DY-T1	- 40 °C to 85 °C	Tape and reel			
Si9986CY-T1-E3	0 °C to 70 °C	Lead (Pb)-free			
Si9986DY-T1-E3	- 40 °C to 85 °C	Tape and reel			
Si9986CY	0 °C to 70 °C	Bulk (tubes)			
Si9986DY	- 40 °C to 85 °C	Duik (tubes)			

Document Number: 70007 S11-0800-Rev. G, 25-Apr-11

<sup>\*</sup> Pb containing terminations are not RoHS compliant, exemptions may apply.

# Vishay Siliconix



ABSOLUTE MAXIMUM RATINGS <sup>a</sup>					
Parameter		Limit	Unit		
Voltage on any Pin with Respect to Ground		- 0.3 to V <sub>DD</sub> + 0.3			
Voltage on Pins 5, 8 with Respect to Ground		- 1 to V <sub>DD</sub> + 1	V		
Voltage on Pins 1, 4	- 0.3 to GND + 1				
Peak Output Current		1.5	A		
Storage Temperature		- 65 to 150	°C		
Maximum Junction Temperature (T <sub>J</sub> )	150				
Maximum V <sub>DD</sub>		15	V		
Power Dissipation <sup>b</sup>	1	W			
$\Theta_{JA}$		100	°C/W		
Operating Temperature Range	Si9986CY	0 to 70	°C		
Operating reinperature harrye	Si9986DY	- 45 to 85			

#### Notes:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING RANGE					
Parameter	Limit	Unit			
V <sub>DD</sub>	3.8 to 13.2	V			
Maximum Junction Temperature (T <sub>J</sub> )	125	°C			

SPECIFICATIONS								
		Test Conditions Unless Otherwise Specified V <sub>DD</sub> = 3.8 to 13.2 V		Unless Otherwise Specified C Suffix, 0 °C to 70 °C				
Parameter	Symbol	S <sub>A</sub> at GND, S <sub>B</sub> at GND		Min <sup>a</sup>	Typ <sup>b</sup>	Max <sup>a</sup>	Unit	
Input					'			
Input Voltage High	$V_{INH}$			2			V	
Input Voltage Low	$V_{INL}$					1	v	
Input Current with Input Voltage High	I <sub>INH</sub>	$V_{IN} = 2$	2 V			1	μΑ	
Input Current with Input Voltage Low	I <sub>INL</sub>	$V_{IN} = 0$	) V	- 1			μΑ	
Output								
		I <sub>OUT</sub> = - 500 mA	V <sub>DD</sub> = 10.8 V	10.5	10.7			
Output Voltage High	V <sub>OUTH</sub>		$V_{DD} = 4.5 \text{ V}$	4.1	4.3			
		I <sub>OUT</sub> = - 300 mA, V <sub>DD</sub> = 3.8 V		3.4	3.7		v	
	V <sub>OUTL</sub>	I <sub>OUT</sub> = 500 mA -	V <sub>DD</sub> = 10.8 V		0.2	0.3	V	
Output Voltage Low			$V_{DD} = 4.5 \text{ V}$		0.2	0.4		
		$I_{OUT} = 300 \text{ mA},$	$V_{DD} = 3.8 \text{ V}$		0.1	0.4		
Output Leakage Current High	I <sub>OLH</sub>	$IN_A = IN_B \ge 2 \text{ V}, V_{OU}$	<sub>T</sub> = V <sub>DD</sub> = 13.2 V	- 10	0		μΑ	
Output Leakage Current Low	I <sub>OLL</sub>	$V_{OUT} = 0, V_{DI}$	<sub>O</sub> = 13.2 V		0	10	μΑ	
Output V Clamp High	$V_{CLH}$	$IN_A = IN_B \ge 2 \text{ V}$	I <sub>OUT</sub> = 100 mA		$V_{DD} + 0.7$		V	
Output V Clamp Low	$V_{CLL}$	1144 - 1148 = 5 A	I <sub>OUT</sub> = - 100 mA		- 0.7		]	
Supply								
V <sub>DD</sub> Supply Current	I <sub>DD</sub>	$IN = 100 \text{ kHz}, V_{DD} = 5 \text{ V}$			2		mA	
VDD Supply Surrent	טטי	$IN_A = IN_B = 4.5 \text{ V}, V_{DD} = 5.5 \text{ V}$		_		300	μΑ	
Dynamic								
Propogation Delay Time	T <sub>PLH</sub>	V <sub>DD</sub> = 5 V			300		nS	
1 Topogation Dolay Time	$T_{PHL}$				100	-	110	

#### Notes:

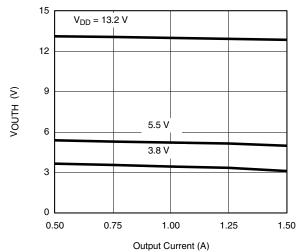
a. Device mounted with all leads soldered or welded to PC board. b. Derate 10 mW/°C above 25 °C.

a. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

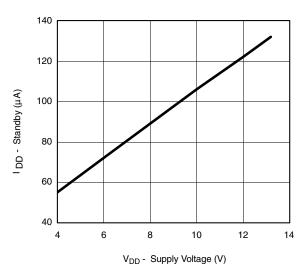
b. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.



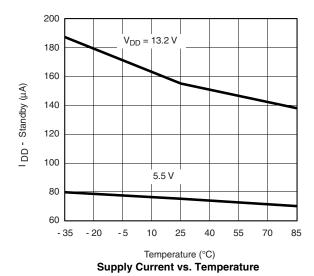
### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Output High Voltage vs. Output Current



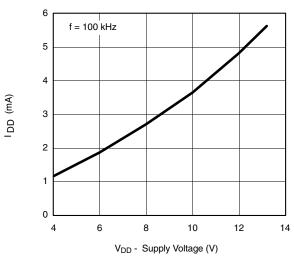
Supply Current vs. Supply Voltage



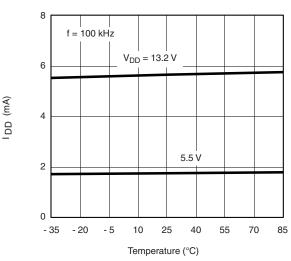
700 600 500 VOUTL (mV) 400  $V_{DD} = 3.8 \text{ V}$ 13.2 V 300 200 100 0 0.50 0.75 1.00 1.25 1.50

Output Current (A)

Output Low Voltage vs. Output Current



Supply Current vs. Supply Voltage

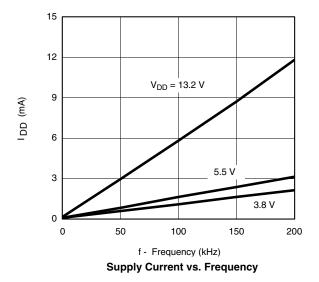


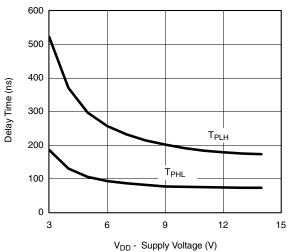
Supply Current vs. Temperature

# Vishay Siliconix



### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)





Propagation Time vs. Supply Voltage

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?70007.



SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







	MILLIM	IETERS	INCHES	
DIM	Min	Max	Min	Max
Α	1.35	1.75	0.053	0.069
A <sub>1</sub>	0.10	0.20	0.004	0.008
В	0.35	0.51	0.014	0.020
С	0.19	0.25	0.0075	0.010
D	4.80	5.00	0.189	0.196
Е	3.80	4.00	0.150	0.157
е	1.27 BSC		0.050 BSC	
Н	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.020
L	0.50	0.93	0.020	0.037
q	0°	8°	0°	8°
S	0.44	0.64	0.018	0.026
ECN: C-06527-Rev. I. 11-Sep-06				

DWG: 5498

Document Number: 71192 www.vishay.com 11-Sep-06



# **Legal Disclaimer Notice**

Vishay

## **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.